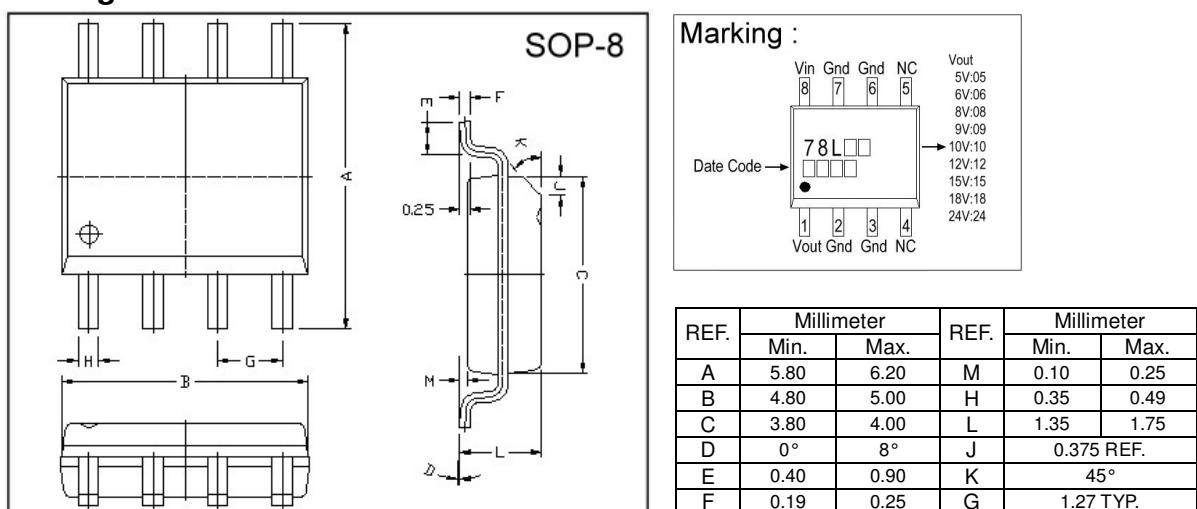


GSC78LXX**POSITIVE VOLTAGE REGULATOR****Description**

The GSC78LXX series of positive regulators are available in the SOP-8 package and with 5V, 6V, 8V, 9V, 10V, 12V, 15V, 18V and 24V fixed output voltages, making it useful in a wide range of applications. These regulators can provide local on-card regulation, eliminating the distribution problems associated with single point regulation. Each type employs internal current limiting, thermal shut-down and safe operating area protection, making it essentially indestructible. If adequate heat sinking is provided, they can deliver over 100mA output current. Although designed primarily as fixed voltage regulators, these devices can be used with external components to obtain adjustable voltages and currents. GSC78LXX is characterized for operation from 0°C to +125°C.

Features

- Internal Short-Circuit Current Limiting
- Internal Thermal Overload Protection
- No External Components Required

Package Dimensions**Absolute Maximum Ratings**

Parameter	Ratings	Unit
Input voltage	GSC78L05 ~ 10	30
	GSC78L12 ~ 18	35
	GSC78L24	40
Output current	100	mA
Operating junction temperature range	0 ~ 125	°C
Storage temperature range	-55 ~ 150	°C
Power Dissipation	750*	mW

*When tested in free air condition, without heat sinking.

GTM CORPORATION

ISSUED DATE :2006/01/17
REVISED DATE :2006/06/21C

Electrical Characteristics

GSC78L05 (Refer to the test circuits, $T_j=0\sim125^\circ C$, $I_o=40mA$, $V_{in}=10V$, $C_{in}=0.33\mu F$, $C_{o}=0.1\mu F$ unless otherwise specified)

Symbol		Min.	Typ.	Max.	Unit	Test Conditions
VO	A-Rank (3%)	4.85	5.0	5.15	V	$V_{in}=10V$, $I_o=40mA$, $T_j=25^\circ C$ $7V \leq V_{in} \leq 20V$, $1mA \leq I_o \leq 40mA$ $7V \leq V_{in} \leq V_{max}$, $1mA \leq I_o \leq 70mA$ (Note2)
	B-Rank (5%)	4.75	-	5.25		
ΔV_{O} (Line Regulation)	-	18	75	mV	$7V \leq V_{in} \leq 20V$, $I_o=40mA$, $T_j=25^\circ C$	
	-	10	54		$8V \leq V_{in} \leq 20V$, $I_o=40mA$, $T_j=25^\circ C$	
ΔV_{O} (Load Regulation)	-	20	60	mV	$V_{in}=10V$, $1mA \leq I_o \leq 100mA$, $T_j=25^\circ C$	
	-	5	30		$V_{in}=10V$, $1mA \leq I_o \leq 40mA$, $T_j=25^\circ C$	
IQ	-	3.0	5.0	mA	$V_{in}=10V$, $I_o=0mA$, $T_j=25^\circ C$	
ΔIQ	-	-	0.1	mA	$V_{in}=10V$, $1mA \leq I_o \leq 40mA$	
	-	-	1.0		$8V \leq V_{in} \leq 20V$, $I_o=40mA$	
Vn	-	40	-	µV	$10Hz \leq f \leq 100KHz$	
RR	47	62	-	dB	$8V \leq V_{in} \leq 20V$, $f=120Hz$, $T_j=25^\circ C$	
VD	-	1.7	-	V	$I_o=100mA$, $T_j=25^\circ C$	
$\Delta V_{o} / \Delta T_j$	-	-0.65	-	mV/°C	$I_o=5mA$, $0^\circ C \leq T_j \leq 125^\circ C$	

GSC78L06 (Refer to the test circuits, $T_j=0\sim125^\circ C$, $I_o=40mA$, $V_{in}=12V$, $C_{in}=0.33\mu F$, $C_{o}=0.1\mu F$ unless otherwise specified)

Symbol		Min.	Typ.	Max.	Unit	Test Conditions
VO	A-Rank (3%)	5.82	6.0	6.18	V	$V_{in}=12V$, $I_o=40mA$, $T_j=25^\circ C$ $8.5V \leq V_{in} \leq 20V$, $1mA \leq I_o \leq 40mA$ $8.5V \leq V_{in} \leq V_{max}$, $1mA \leq I_o \leq 70mA$ (Note2)
	B-Rank (5%)	5.70	-	6.30		
ΔV_{O} (Line Regulation)	-	64	175	mV	$8.5V \leq V_{in} \leq 20V$, $I_o=40mA$, $T_j=25^\circ C$	
	-	54	125		$9V \leq V_{in} \leq 20V$, $I_o=40mA$, $T_j=25^\circ C$	
ΔV_{O} (Load Regulation)	-	12.8	80	mV	$V_{in}=12V$, $1mA \leq I_o \leq 100mA$, $T_j=25^\circ C$	
	-	5.8	40		$V_{in}=12V$, $1mA \leq I_o \leq 70mA$, $T_j=25^\circ C$	
IQ	-	3.9	6.0	mA	$V_{in}=12V$, $I_o=0mA$, $T_j=25^\circ C$	
ΔIQ	-	-	0.1	mA	$V_{in}=12V$, $1mA \leq I_o \leq 40mA$	
	-	-	1.5		$9V \leq V_{in} \leq 20V$, $I_o=40mA$	
Vn	-	49	-	µV	$10Hz \leq f \leq 100KHz$	
RR	40	46	-	dB	$10V \leq V_{in} \leq 20V$, $f=120Hz$, $T_j=25^\circ C$	
VD	-	1.7	-	V	$I_o=100mA$, $T_j=25^\circ C$	
$\Delta V_{o} / \Delta T_j$	-	0.75	-	mV/°C	$I_o=5mA$, $0^\circ C \leq T_j \leq 125^\circ C$	

GSC78L08 (Refer to the test circuits, $T_j=0\sim125^\circ C$, $I_o=40mA$, $V_{in}=14V$, $C_{in}=0.33\mu F$, $C_{o}=0.1\mu F$ unless otherwise specified)

Symbol		Min.	Typ.	Max.	Unit	Test Conditions
VO	A-Rank (3%)	7.76	8.0	8.24	V	$V_{in}=14V$, $I_o=40mA$, $T_j=25^\circ C$ $10.5V \leq V_{in} \leq 23V$, $1mA \leq I_o \leq 40mA$ $10.5V \leq V_{in} \leq V_{max}$, $1mA \leq I_o \leq 70mA$ (Note2)
	B-Rank (5%)	7.60	-	8.40		
ΔV_{O} (Line Regulation)	-	10	175	mV	$10.5V \leq V_{in} \leq 23V$, $I_o=40mA$, $T_j=25^\circ C$	
	-	8	125		$11V \leq V_{in} \leq 23V$, $I_o=40mA$, $T_j=25^\circ C$	
ΔV_{O} (Load Regulation)	-	15	80	mV	$V_{in}=14V$, $1mA \leq I_o \leq 100mA$, $T_j=25^\circ C$	
	-	8	40		$V_{in}=14V$, $1mA \leq I_o \leq 70mA$, $T_j=25^\circ C$	
IQ	-	2.0	5.5	mA	$V_{in}=14V$, $I_o=0mA$, $T_j=25^\circ C$	
ΔIQ	-	-	0.1	mA	$V_{in}=14V$, $1mA \leq I_o \leq 40mA$	
	-	-	1.5		$11V \leq V_{in} \leq 23V$, $I_o=40mA$	
Vn	-	49	-	µV	$10Hz \leq f \leq 100KHz$	
RR	39	45	-	dB	$11V \leq V_{in} \leq 21V$, $f=120Hz$, $T_j=25^\circ C$	
VD	-	1.7	-	V	$I_o=100mA$, $T_j=25^\circ C$	
$\Delta V_{o} / \Delta T_j$	-	0.75	-	mV/°C	$I_o=5mA$, $0^\circ C \leq T_j \leq 125^\circ C$	

GTM CORPORATION

ISSUED DATE :2006/01/17
REVISED DATE :2006/06/21C

GSC78L09 (Refer to the test circuits, Tj=0~125°C, Io=40mA, Vin=15V, Cin=0.33μF, Co=0.1μF unless otherwise specified)

Symbol		Min.	Typ.	Max.	Unit	Test Conditions
VO	A-Rank (3%)	8.73	9.0	9.27	V	Vin=15V, Io=40mA, Tj=25°C 11.5V ≤ Vin ≤ 24V, 1mA ≤ Io ≤ 40mA 11.5V ≤ Vin ≤ Vmax, 1mA ≤ Io ≤ 70mA (Note2)
	B-Rank (5%)	8.55	-	9.45		
ΔVO (Line Regulation)	-	90	200	mV	11.5V ≤ Vin ≤ 24V, Io=40mA, Tj=25°C	
	-	100	150		13V ≤ Vin ≤ 24V, Io=40mA, Tj=25°C	
ΔVO (Load Regulation)	-	20	90	mV	Vin=15V, 1mA ≤ Io ≤ 100mA, Tj=25°C	
	-	10	45		Vin=15V, 1mA ≤ Io ≤ 40mA, Tj=25°C	
IQ	-	2.0	6.0	mA	Vin=15V, Io=0mA, Tj=25°C	
Δ IQ	-	-	0.1	mA	Vin=15V, 1mA ≤ Io ≤ 40mA	
	-	-	1.5		13V ≤ Vin ≤ 24V, Io=40mA	
Vn	-	49	-	μV	10Hz ≤ f ≤ 100KHz	
RR	38	44	-	dB	12V ≤ Vin ≤ 23V, f=120Hz, Tj=25°C	
VD	-	1.7	-	V	Io=100mA, Tj=25°C	
ΔVo / ΔTj	-	0.75	-	mV/°C	Io=5mA, 0°C ≤ Tj ≤ 125°C	

GSC78L10 (Refer to the test circuits, Tj=0~125°C, Io=40mA, Vin=17V, Cin=0.33μF, Co=0.1μF unless otherwise specified)

Symbol		Min.	Typ.	Max.	Unit	Test Conditions
VO	A-Rank (3%)	9.70	10.0	10.30	V	Vin=17V, Io=40mA, Tj=25°C 13V ≤ Vin ≤ 25V, 1mA ≤ Io ≤ 40mA 13V ≤ Vin ≤ Vmax, 1mA ≤ Io ≤ 70mA (Note2)
	B-Rank (5%)	9.50	-	10.50		
ΔVO (Line Regulation)	-	51	175	mV	13V ≤ Vin ≤ 25V, Io=40mA, Tj=25°C	
	-	42	125		14V ≤ Vin ≤ 25V, Io=40mA, Tj=25°C	
ΔVO (Load Regulation)	-	20	90	mV	Vin=17V, 1mA ≤ Io ≤ 100mA, Tj=25°C	
	-	11	40		Vin=17V, 1mA ≤ Io ≤ 40mA, Tj=25°C	
IQ	-	4.2	6.0	mA	Vin=17V, Io=0mA, Tj=25°C	
Δ IQ	-	-	0.1	mA	Vin=17V, 1mA ≤ Io ≤ 40mA	
	-	-	1.5		14V ≤ Vin ≤ 25V, Io=40mA	
Vn	-	62	-	μV	10Hz ≤ f ≤ 100KHz	
RR	37	44	-	dB	15V ≤ Vin ≤ 25V, f=120Hz, Tj=25°C	
VD	-	1.7	-	V	Io=100mA, Tj=25°C	

GSC78L12 (Refer to the test circuits, Tj=0~125°C, Io=40mA, Vin=19V, Cin=0.33μF, Co=0.1μF unless otherwise specified)

Symbol		Min.	Typ.	Max.	Unit	Test Conditions
VO	A-Rank (3%)	11.64	12.0	12.36	V	Vin=19V, Io=40mA, Tj=25°C 14.5V ≤ Vin ≤ 27V, 1mA ≤ Io ≤ 40mA 14.5V ≤ Vin ≤ Vmax, 1mA ≤ Io ≤ 70mA (Note2)
	B-Rank (5%)	11.40	-	12.60		
ΔVO (Line Regulation)	-	25	300	mV	14.5V ≤ Vin ≤ 27V, Io=40mA, Tj=25°C	
	-	20	250		16V ≤ Vin ≤ 27V, Io=40mA, Tj=25°C	
ΔVO (Load Regulation)	-	25	150	mV	Vin=19V, 1mA ≤ Io ≤ 100mA, Tj=25°C	
	-	12	75		Vin=19V, 1mA ≤ Io ≤ 40mA, Tj=25°C	
IQ	-	2.0	6.0	mA	Vin=19V, Io=0mA, Tj=25°C	
Δ IQ	-	-	0.1	mA	Vin=19V, 1mA ≤ Io ≤ 40mA	
	-	-	1.5		16V ≤ Vin ≤ 27V, Io=40mA	
Vn	-	80	-	μV	10Hz ≤ f ≤ 100KHz	
RR	37	65	-	dB	15V ≤ Vin ≤ 25V, f=120Hz, Tj=25°C	
VD	-	1.7	-	V	Io=100mA, Tj=25°C	
ΔVo / ΔTj	-	-1.0	-	mV/°C	Io=5mA, 0°C ≤ Tj ≤ 125°C	

GTM CORPORATION

ISSUED DATE :2006/01/17
REVISED DATE :2006/06/21C

GSC78L15 (Refer to the test circuits, Tj=0~125°C, Io=40mA, Vin=23V, Cin=0.33μF, Co=0.1μF unless otherwise specified)

Symbol		Min.	Typ.	Max.	Unit	Test Conditions
VO	A-Rank (3%)	14.55	15.0	15.45	V	Vin=23V, Io=40mA, Tj=25°C 17.5V ≤ Vin ≤ 30V, 1mA ≤ Io ≤ 40mA 17.5V ≤ Vin ≤ Vmax, 1mA ≤ Io ≤ 70mA (Note2)
	B-Rank (5%)	14.25	-	15.75		
ΔVO (Line Regulation)	-	25	150	mV	17.5V ≤ Vin ≤ 30V, Io=40mA, Tj=25°C	
	-	15	75		20V ≤ Vin ≤ 30V, Io=40mA, Tj=25°C	
ΔVO (Load Regulation)	-	20	150	mV	Vin=23V, 1mA ≤ Io ≤ 100mA, Tj=25°C	
	-	25	150		Vin=23V, 1mA ≤ Io ≤ 70mA, Tj=25°C	
IQ	-	2.2	6.5	mA	Vin=23V, Io=0mA, Tj=25°C	
ΔIQ	-	-	0.1	mA	Vin=23V, 1mA ≤ Io ≤ 40mA	
	-	-	1.5		20V ≤ Vin ≤ 30V, Io=40mA	
Vn	-	90	-	μV	10Hz ≤ f ≤ 100KHz	
RR	34	63	-	dB	18.5V ≤ Vin ≤ 28.5V, f=120Hz, Tj=25°C	
VD	-	1.7	-	V	Io=100mA, Tj=25°C	
$\Delta Vo / \Delta Tj$	-	-1.3	-	mV/°C	Io=5mA, 0°C ≤ Tj ≤ 125°C	

GSC78L18 (Refer to the test circuits, Tj=0~125°C, Io=40mA, Vin=27V, Cin=0.33μF, Co=0.1μF unless otherwise specified)

Symbol		Min.	Typ.	Max.	Unit	Test Conditions
VO	A-Rank (3%)	17.46	18.0	18.54	V	Vin=27V, Io=40mA, Tj=25°C 21V ≤ Vin ≤ 33V, 1mA ≤ Io ≤ 40mA 21V ≤ Vin ≤ Vmax, 1mA ≤ Io ≤ 70mA (Note2)
	B-Rank (5%)	17.10	-	18.9		
ΔVO (Line Regulation)	-	145	300	mV	21V ≤ Vin ≤ 33V, Io=40mA, Tj=25°C	
	-	135	250		22V ≤ Vin ≤ 33V, Io=40mA, Tj=25°C	
ΔVO (Load Regulation)	-	30	170	mV	Vin=27V, 1mA ≤ Io ≤ 100mA, Tj=25°C	
	-	15	85		Vin=27V, 1mA ≤ Io ≤ 40mA, Tj=25°C	
IQ	-	2.0	6.0	mA	Vin=27V, Io=0mA, Tj=25°C	
ΔIQ	-	-	0.1	mA	Vin=27V, 1mA ≤ Io ≤ 40mA	
	-	-	1.5		21V ≤ Vin ≤ 33V, Io=40mA	
Vn	-	150	-	μV	10Hz ≤ f ≤ 100KHz	
RR	34	48	-	dB	23V ≤ Vin ≤ 33V, f=120Hz, Tj=25°C	
VD	-	1.7	-	V	Io=100mA, Tj=25°C	
$\Delta Vo / \Delta Tj$	-	-1.8	-	mV/°C	Io=5mA, 0°C ≤ Tj ≤ 125°C	

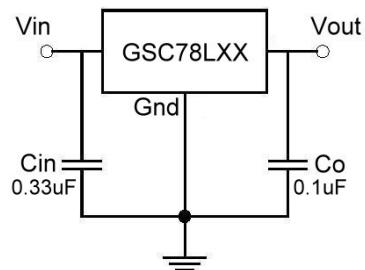
GSC78L24 (Refer to the test circuits, Tj=0~125°C, Io=40mA, Vin=33V, Cin=0.33μF, Co=0.1μF unless otherwise specified)

Symbol		Min.	Typ.	Max.	Unit	Test Conditions
VO	A-Rank (3%)	23.28	24.0	24.72	V	Vin=33V, Io=40mA, Tj=25°C 27V ≤ Vin ≤ 38V, 1mA ≤ Io ≤ 40mA 27V ≤ Vin ≤ Vmax, 1mA ≤ Io ≤ 70mA (Note2)
	B-Rank (5%)	22.80	-	25.20		
ΔVO (Line Regulation)	-	160	300	mV	27V ≤ Vin ≤ 38V, Io=40mA, Tj=25°C	
	-	150	250		28V ≤ Vin ≤ 38V, Io=40mA, Tj=25°C	
ΔVO (Load Regulation)	-	40	200	mV	Vin=33V, 1mA ≤ Io ≤ 100mA, Tj=25°C	
	-	20	100		Vin=33V, 1mA ≤ Io ≤ 40mA, Tj=25°C	
IQ	-	2.2	6.0	mA	Vin=33V, Io=0mA, Tj=25°C	
ΔIQ	-	-	0.1	mA	Vin=33V, 1mA ≤ Io ≤ 40mA	
	-	-	1.5		27V ≤ Vin ≤ 38V, Io=40mA	
Vn	-	200	-	μV	10Hz ≤ f ≤ 100KHz	
RR	34	45	-	dB	27V ≤ Vin ≤ 38V, f=120Hz, Tj=25°C	
VD	-	1.7	-	V	Io=100mA, Tj=25°C	
$\Delta Vo / \Delta Tj$	-	-2.0	-	mV/°C	Io=5mA, 0°C ≤ Tj ≤ 125°C	

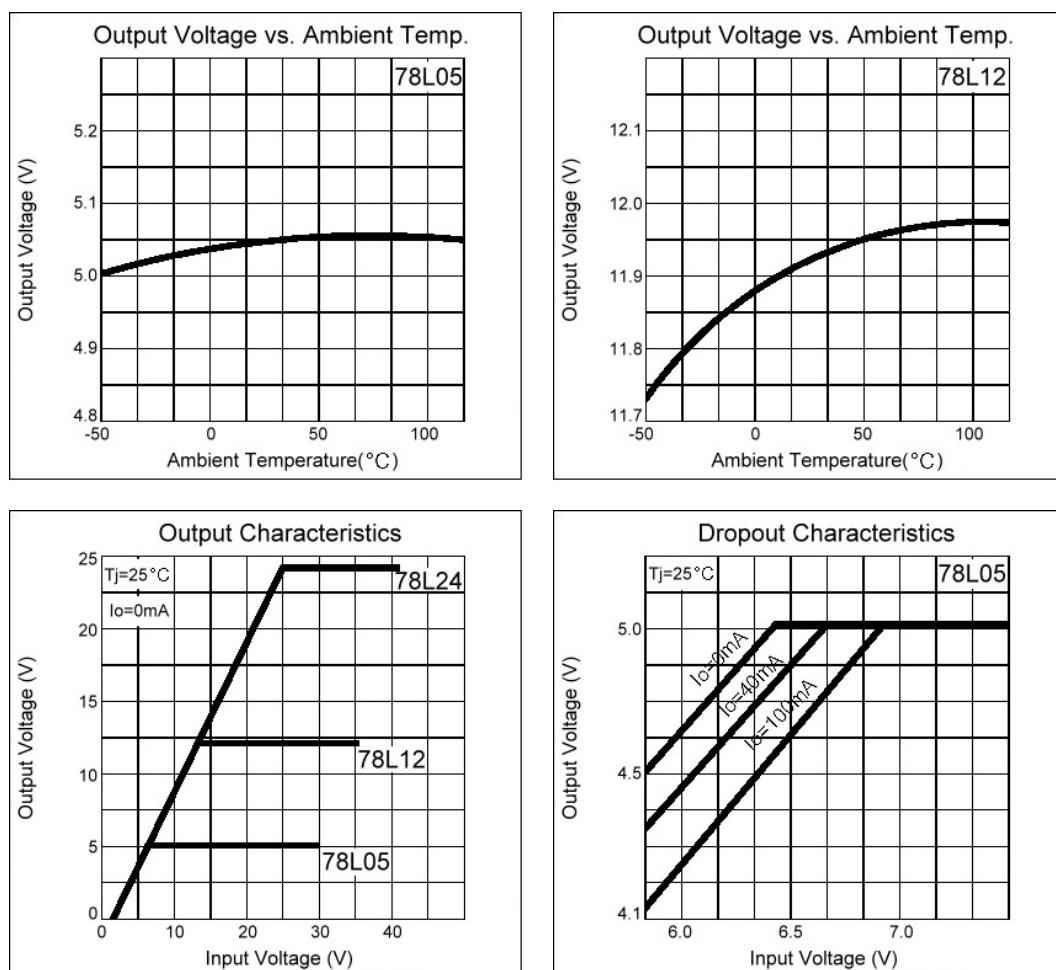
Note1: The Maximum steady state usable output current is dependent on input voltage, heat sinking, lead length of the package and copper of PCB .The data above represent pulse test conditions with junction temperatures specified at the initiation of test.

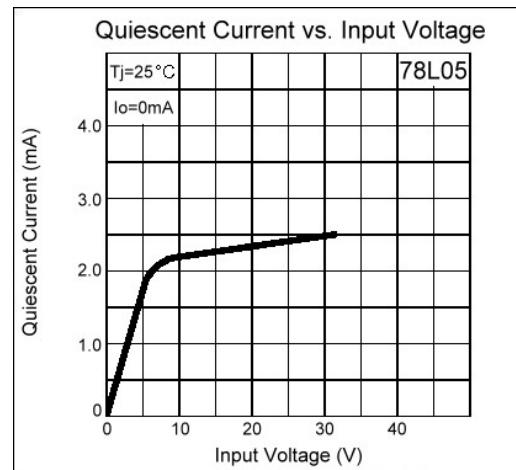
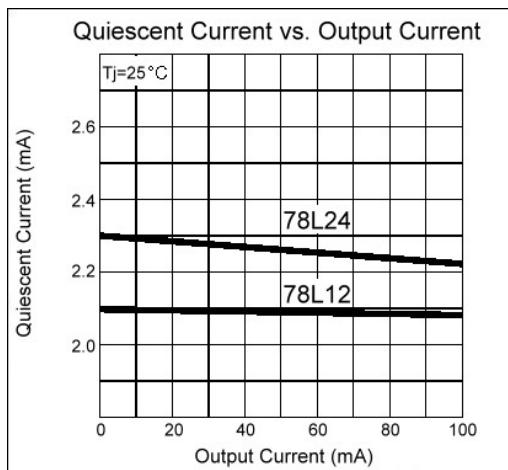
Note2: Power dissipation<0.75W

Typical Application



Characteristics Curve





Important Notice:

- All rights are reserved. Reproduction in whole or in part is prohibited without the prior written approval of GTM.
- GTM reserves the right to make changes to its products without notice.
- GTM semiconductor products are not warranted to be suitable for use in life-support Applications, or systems.
- GTM assumes no liability for any consequence of customer product design, infringement of patents, or application assistance.

Head Office And Factory:

- **Taiwan:** No. 17-1 Tatung Rd. Fu Kou Hsin-Chu Industrial Park, Hsin-Chu, Taiwan, R. O. C.
TEL : 886-3-597-7061 FAX : 886-3-597-9220, 597-0785
- **China:** (201203) No.255, Jang-Jiang Tsai-Lueng RD. , Pu-Dung-Hsin District, Shang-Hai City, China
TEL : 86-21-5895-7671 ~ 4 FAX : 86-21-38950165